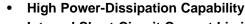


POSITIVE-VOLTAGE REGULATORS

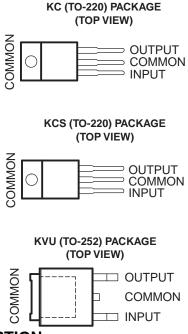
Check for Samples: uA78M00 SERIES

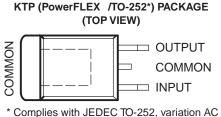
FEATURES

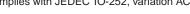
- 3-Terminal Regulators
- Output Current up to 500 mA
- No External Components
- Internal Thermal-Overload Protection

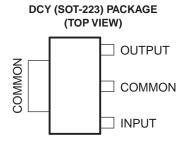


- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation









DESCRIPTION

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

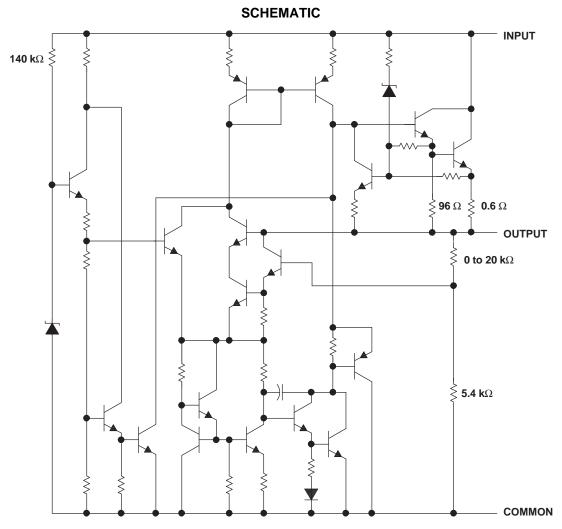
ORDERING INFORMATION

For package and ordering information, see the Package Option Addendum at the end of this document.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





Resistor values shown are nominal.



Absolute Maximum Ratings(1)

over virtual junction temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{I}	Input voltage		35	V
T_J	Operating virtual junction temperature		150	°C
T _{stg}	Storage temperature range	-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Package Thermal Data(1)

PACKAGE	BOARD	θ _{JP} ⁽²⁾	θ _{JC}	θ_{JA}
PowerFLEX/TO-252 - KTP	High K, JESD 51-5	1.4°C/W	19°C/W	28°C/W
SOT-223 – DCY	High K, JESD 51-7		30.6°C/W	53°C/W
TO-220 – KC	High K, JESD 51-5	3°C/W	17°C/W	19°C/W
TO-220 – KCS	High K, JESD 51-5	3°C/W	17°C/W	19°C/W
TO-252 – KVU	High K, JESD 51-5			30.3°C/W

Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. For packages with exposed thermal pads, such as QFN, PowerPADTM, or PowerFLEX, θ_{JP} is defined as the thermal resistance between

Recommended Operating Conditions

			MIN	MAX	UNIT
		uA78M33	5.3	25	
		uA78M05	7	25	
		uA78M06	8	25	
M. Janut valta va	land valence	uA78M08	10.5	25	
VI	Input voltage	uA78M09	11.5	26	V
		uA78M10	12.5	28	
		uA78M12	14.5	30	
		uA78M15	17.5	30	
Io	Output current			500	mA
т	T. On a setting a sint calling atting to a second control of	uA78MxxC	0	125	°C
T_{J}	Operating virtual junction temperature	uA78MxxI	-40	125	C

the die junction and the bottom of the exposed pad.



at specified virtual junction temperature, V_I = 8 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

DADAMETED	TEG	ST CONDITIONS ⁽¹⁾	uA	78M33C	;	LINUT
PARAMETER	IES	SI CONDITIONS."	MIN	TYP	MAX	UNII
Output voltage ⁽²⁾	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$		3.2	3.3	3.4	WNIT V MV dB mV mV/°C μV V mA mA
Output voltage 7	$V_1 = 8 \text{ V to } 20 \text{ V}$	$T_J = 0$ °C to 125°C	3.1	3.3	3.5	
Input voltage regulation	1 200 m A	V _I = 5.3 V to 25 V		9	100	m)/
	$I_0 = 200 \text{ mA}$	V _I = 8 V to 25 V		3	50	- V - mV - dB - mV - mV/°C - μV - V - mA - mA
Dinale rejection	V _I = 8 V to 18 V,	I _O = 100 mA, T _J = 0°C to 125°C	62			٩D
Ripple rejection	f = 120 Hz	I _O = 300 mA	62	80		mV dB mV mV/°C μV V mA
Output voltage regulation	V _I = 8 V,	I _O = 5 mA to 500 mA		20	100	mV
Temperature coefficient of output voltage	$I_O = 5 \text{ mA},$	$T_J = 0$ °C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
Dies sument shares	I _O = 200 mA, V _I = 8 V to 25	V, T _J = 0°C to 125°C			0.8	A
Bias current change	$I_0 = 5 \text{ mA to } 350 \text{ mA},$	$T_J = 0$ °C to 125°C			0.5	mA
Short-circuit output current	V _I = 35 V			300		mA
Peak output current				700		mA

All characteristics are measured with a $0.33-\mu F$ capacitor across the input and a $0.1-\mu F$ capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately. This specification applies only for dc power dissipation permitted by absolute maximum ratings

Electrical Characteristics

at specified virtual junction temperature, $V_I = 10 \text{ V}$, $I_O = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

DADAMETED	TEG	ST CONDITIONS ⁽¹⁾	uA	78M05C	;	UNIT	
PARAMETER	IES	SI CONDITIONS (7)	MIN	TYP	MAX	UNII	
Output voltage	$I_0 = 5 \text{ mA to } 350 \text{ mA},$		4.8	5	5.2	V	
Output voltage	$V_I = 7 \text{ V to } 20 \text{ V}$	$T_J = 0$ °C to 125°C	4.75		5.25	V	
Input voltage regulation	1 200 m A	$V_I = 7 V \text{ to } 25 V$		3	100	m\/	
	I _O = 200 mA	$V_I = 8 V \text{ to } 25 V$		1	50	V mV dB mV mV/°C μV V mA	
Dinnla raigation	$V_{I} = 8 \text{ V to } 18 \text{ V},$	$I_{O} = 100 \text{ mA}, T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	62			٩D	
Ripple rejection	f = 120 Hz	I _O = 300 mA	62	80		uБ	
Output valta as assulation	$I_O = 5$ mA to 500 mA	·		20	100	m\/	
Output voltage regulation	I _O = 5 mA to 200 mA			10	50	mv	
Temperature coefficient of output voltage	I _O = 5 mA,	T _J = 0°C to 125°C		-1		mV/°C	
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV	
Dropout voltage				2		V	
Bias current				4.5	6	mA	
Bias current change	I _O = 200 mA, V _I = 8 V to 25	V, T _J = 0°C to 125°C			0.8	A	
	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C			0.5	mA	
Short-circuit output current	V _I = 35 V	·		300		mA	
Peak output current				0.7		Α	

All characteristics are measured with a 0.33-µF capacitor across the input and a 0.1-µF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



at specified virtual junction temperature, $V_1 = 10 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

DADAMETED	_	FEAT CONDITIONS(1)	uA78M05I		uA78M05I	
PARAMETER		TEST CONDITIONS ⁽¹⁾	MIN	TYP	MAX	UNIT
Output voltage	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$		4.8	5	5.2	V
Output voltage	$V_1 = 7 \text{ V to } 20 \text{ V}$	$T_J = -40$ °C to 125°C	4.75		5.25	V
land della service della servi	1 200 m A	V _I = 7 V to 25 V		3	100	mV
input voitage regulation	out voltage regulation $I_O = 200 \text{ mA}$	V _I = 8 V to 25 V		1	50	ШУ
Pinnle rejection	V _I = 8 V to 18 V,	I_{O} = 100 mA, T_{J} = -40°C to 125°C	62			dB
Ripple rejection	f = 120 Hz	$I_{O} = 300 \text{ mA}$	62	80		uБ
Output valtage regulation	$I_O = 5$ mA to 500 mA			20	100	m\/
Output voltage regulation	$I_O = 5$ mA to 200 mA			10	50	mV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = -40$ °C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
Dies sument shares	$I_0 = 200 \text{ mA}, V_1 = 8 \text{ V to } 200 \text{ mA}$	25 V, T _J = -40°C to 125°C			8.0	A
Bias current change	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$	$T_J = -40$ °C to 125°C			0.5	mA
Short-circuit output current	V _I = 35 V			300		mA
Peak output current				0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

Electrical Characteristics

at specified virtual junction temperature, V_I = 11 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

DADAMETED		TEST CONDITIONS(1)	uA78M06C		LINUT	
PARAMETER		LEST CONDITIONS	.,	MIN	TYP	MAX	UNIT
Output voltage	L	\/		5.75	6	6.25	V
Output voltage	$I_0 = 5 \text{ mA to } 350 \text{ mA},$	$V_1 = 8 \text{ V to } 21 \text{ V}$	$T_J = 0$ °C to 125°C	5.7		6.3	V
Input voltage regulation	1 200 m A	V _I = 8 V to 25 V			5	100	mV
Input voltage regulation	I _O = 200 mA	$V_{I} = 9 V \text{ to } 25 V$			1.5	50	IIIV
Ripple rejection	V _I = 8 V to 18 V,	f = 120 Hz	$I_{O} = 100 \text{ mA},$ $T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	59			dB
			$I_O = 300 \text{ mA}$	59	80		
Output voltage regulation	$I_O = 5$ mA to 500 mA					120	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	60	IIIV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				45		μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Diag current change	$V_{I} = 9 V \text{ to } 25 V,$	$I_0 = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			0.8	mA
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	IIIA
Short-circuit output current	V _I = 35 V				270		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a $0.33-\mu F$ capacitor across the input and a $0.1-\mu F$ capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



at specified virtual junction temperature, $V_1 = 14 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

DADAMETED		TEST CONDITIONS(1)		uA	78M08	3C	LINUT
PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	UNIT		
Output voltage	V _I = 10.5 V to 23 V,	$I_0 = 5 \text{ mA to } 350 \text{ mA}$		7.7	8	8.3	V
Output voltage	V ₁ = 10.5 V to 25 V,	1 ₀ = 5 IIIA to 350 IIIA	$T_J = 0$ °C to 125°C	7.6		8.4	V
Input voltage regulation	L = 200 mA	$V_I = 10.5 \text{ V to } 25 \text{ V}$			6	100	mV
Input voltage regulation	I _O = 200 mA	$V_{I} = 11 \text{ V to } 25 \text{ V}$			2	50	IIIV
Pinnla raigation	$V_I = 11 \text{ V to } 21.5 \text{ V},$	$I_0 = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	56			dB
Ripple rejection	f = 120 Hz	$I_{O} = 300 \text{ mA}$		56	80		uБ
Output valtage regulation	$I_O = 5$ mA to 500 mA				25	160	m)/
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	80	mV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				52		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Dies surrent change	$V_I = 10.5 \text{ V to } 25 \text{ V},$	$I_0 = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			8.0	A
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				250		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

Electrical Characteristics

at specified virtual junction temperature, $V_1 = 16 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS(1)		uA78M09C		UNIT	
PARAIVIETER		1E31 CONDITIONS		MIN	TYP	MAX	UNII
Output valtage	V 44 5 V to 24 V			8.6	9	9.4	V
Output voltage	$V_I = 11.5 \text{ V to } 24 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	8.5		9.5	V
logut voltage regulation	1 200 m A	V _I = 11.5 V to 26 V			6	100	mV
Input voltage regulation	I _O = 200 mA	$V_I = 12 \text{ V to } 26 \text{ V}$			2	50	IIIV
Pipple rejection	$V_{I} = 13 \text{ V to } 23 \text{ V},$	$I_0 = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	56			dB
Ripple rejection	f = 120 Hz	$I_O = 300 \text{ mA}$		56	80		uБ
Output voltage regulation	$I_O = 5$ mA to 500 mA				25	180	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	90	mv
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				58		μV
Dropout voltage					2		٧
Bias current					4.6	6	mA
Dies surrent change	$V_I = 11.5 \text{ V to } 26 \text{ V},$	$I_0 = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			8.0	A
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				250		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.



at specified virtual junction temperature, $V_1 = 17 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

DADAMETED		TEST CONDITIONS(1)		uA	uA78M10C		
PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	UNIT		
Outrot valta aa	V = 12 5 V to 25 V	L = Ε mΛ to 2Ε0 mΛ		9.6	10	10.4	V
Output voltage	$V_{I} = 12.5 \text{ V to } 25 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	9.5		10.5	V
Innut voltage regulation	1 200 m A	$V_{I} = 12.5 \text{ V to } 28 \text{ V}$			7	100	mV
Input voltage regulation	I _O = 200 mA	$V_{I} = 14 \text{ V to } 28 \text{ V}$			2	50	
Dinale rejection	$V_1 = 15 \text{ V to } 25 \text{ V},$	$I_{O} = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	59			dB
Ripple rejection	f = 120 Hz	I _O = 300 mA		55	80	5 200	ав
Output valtage regulation	$I_O = 5$ mA to 500 mA				25	200	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	100	
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				64		μV
Dropout voltage					2		V
Bias current					4.7	6	mA
Dies summent about	V _I = 12.5 V to 28 V,	I _O = 200 mA,	$T_J = 0$ °C to 125°C			0.8	^
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				245		mA
Peak output current		·			0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

Electrical Characteristics

at specified virtual junction temperature, $V_1 = 19 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS(1)		uA78M12C		LINUT	
PARAMETER		1E31 CONDITIONS		MIN	TYP	MAX	UNIT
Output valtage	\/ 14 5 \/ to 27 \/			11.5	12	12.5	V
Output voltage	$V_I = 14.5 \text{ V to } 27 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	11.4		12.6	V
logut voltage regulation	1 200 m A	$V_I = 14.5 \text{ V to } 30 \text{ V}$			8	100	~\/
Input voltage regulation	I _O = 200 mA	$V_I = 16 \text{ V to } 30 \text{ V}$			2	2 50	mv
Dinale rejection	$V_1 = 15 \text{ V to } 25 \text{ V},$	$I_0 = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	55			ر ت
Ripple rejection	f = 120 Hz	$I_O = 300 \text{ mA}$		55	80		V
Outrot valta as as as addition	I _O = 5 mA to 500 mA				25	240	\/
Output voltage regulation	I _O = 5 mA to 200 mA				10	120	mv
Temperature coefficient of output voltage	I _O = 5 mA,	T _J = 0°C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				75		μV
Dropout voltage					2		V
Bias current					4.8	6	mA
Dies surrent change	$V_I = 14.5 \text{ V to } 30 \text{ V},$	$I_0 = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			8.0	A
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	MA
Short-circuit output current	V _I = 35 V				240		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33- μ F capacitor across the input and a 0.1- μ F capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

SLVS059S -JUNE 1976-REVISED MAY 2013



REVISION HISTORY

Changes from Revision Q (April 2010) to Revision R		
Removed obsolete part information from document.	1	
Changes from Revision R (February 2013) to Revision S	Page	
Removed ordering information table.	1	





21-May-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
UA78M05CDCY	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CDCYG3	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CDCYRG3	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125	UA78M05C	
UA78M05CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M05C	Samples
UA78M05CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M05C	Samples
UA78M05CKTPR	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M05C	
UA78M05CKTPRG3	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M05C	
UA78M05CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M05C	Sample
UA78M05IDCY	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	J5	Samples
UA78M05IDCYG3	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	J5	Sample
UA78M05IDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	J5	Sample
UA78M05IDCYRG3	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	J5	Sample
UA78M05IKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	-40 to 125	UA78M05I	
UA78M05IKCE3	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	-40 to 125	UA78M05I	
UA78M05IKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type -40 to 125		UA78M05I	Sample
UA78M05IKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	-40 to 125	UA78M05I	Sample
UA78M05IKTPR	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	-40 to 125	UA78M05I	
UA78M05IKTPRG3	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	-40 to 125	UA78M05I	





www.ti.com

21-May-2013

Orderable Device		Package Type	Package Type Package Pins Package Cty Pack		_		Lead/Ball Finish	•	Op Temp (°C)	Device Marking (4/5)	Samples
UA78M05IKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 125	78M05I	Samples
UA78M06CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125		
UA78M06CKTPR	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M06C	
UA78M06CKTPRG3	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M06C	
UA78M06CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M06C	Samples
UA78M08CDCY	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08CDCYG3	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08CDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08CDCYRG3	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125	UA78M08C	
UA78M08CKCE3	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125	UA78M08C	
UA78M08CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type 0 to 125		UA78M08C	Samples
UA78M08CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M08C	Samples
UA78M08CKTPR	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M08C	
UA78M08CKTPRG3	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M08C	
UA78M08CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M08C	Samples
UA78M09CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125		
UA78M09CKTP	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125		
UA78M09CKTPR	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M09C	
UA78M09CKTPRG3	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M09C	
UA78M09CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M09C	Samples
UA78M10CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125		
UA78M10CKTPR	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M10C	
UA78M10CKTPRG3	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M10C	





21-May-2013

Orderable Device		Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish		Op Temp (°C)	Device Marking	Sample
UA78M10CKVURG3	ACTIVE	TO-252	KVU	3	2500	(2) Green (RoHS	CU SN	(3) Level-3-260C-168 HR	0 to 125	(4/5) 78M10C	Sample
						& no Sb/Br)					Sample
UA78M12CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125	UA78M12C	
UA78M12CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M12C	Sampl
UA78M12CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M12C	Sampl
UA78M12CKTPR	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M12C	
UA78M12CKTPRG3	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M12C	
UA78M12CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR 0 to 125		78M12C	Samp
UA78M33CDCY	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR 0 to 125		C3	Samp
UA78M33CDCYG3	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR 0 to 125		C3	Samp
UA78M33CDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C3	Samp
UA78M33CDCYRG3	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C3	Samp
UA78M33CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125	UA78M33C	
UA78M33CKCE3	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI	0 to 125	UA78M33C	
UA78M33CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M33C	Samp
UA78M33CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type 0 to 125		UA78M33C	Samp
UA78M33CKTPR	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M33C	
UA78M33CKTPRG3	OBSOLETE	PFM	KTP	2		TBD	Call TI	Call TI	0 to 125	UA78M33C	
UA78M33CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M33C	Samp

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.





21-May-2013

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF UA78M05, UA78M10, UA78M33:

Automotive: UA78M05-Q1, UA78M10-Q1, UA78M33-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

www.ti.com 29-May-2013

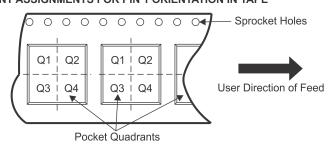
TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO W Cavity AO

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

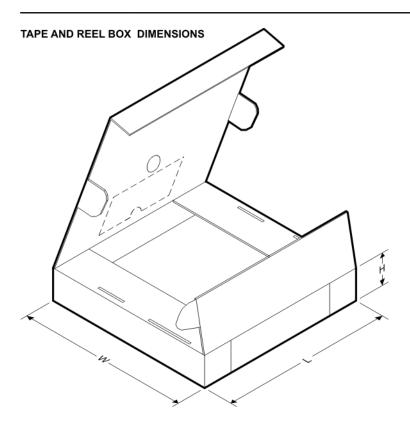


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UA78M05CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M05IDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M05IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M06CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M08CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M08CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M09CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M10CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M12CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M33CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M33CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2

PACKAGE MATERIALS INFORMATION

www.ti.com 29-May-2013

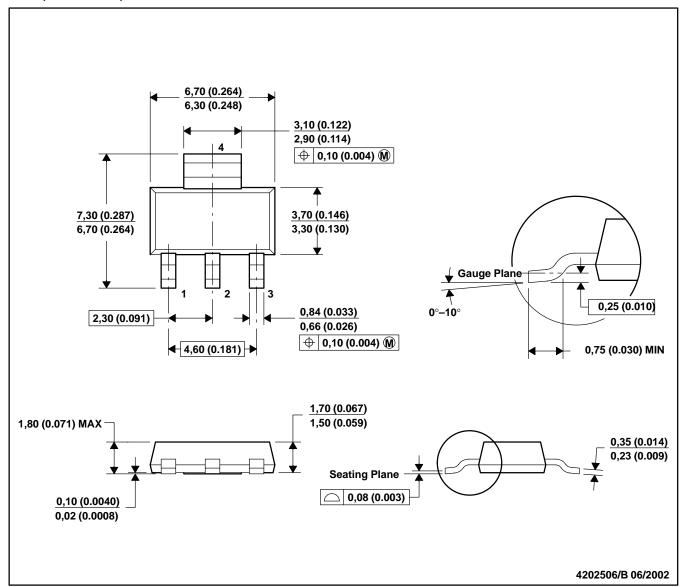


*All dimensions are nominal

All difficusions are nominal							•
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UA78M05CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M05CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M05IDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M05IKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M06CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M08CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M08CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M09CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M10CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M12CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M33CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M33CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0

DCY (R-PDSO-G4)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters (inches).

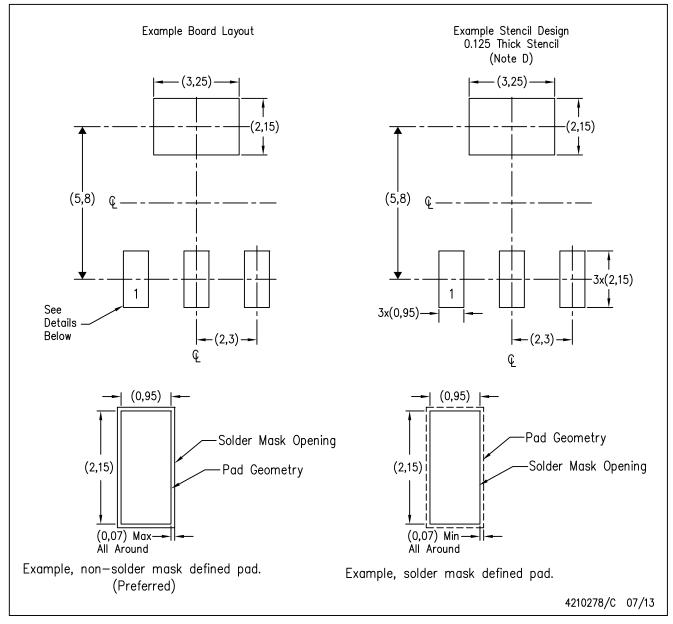
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion.

D. Falls within JEDEC TO-261 Variation AA.

DCY (R-PDSO-G4)

PLASTIC SMALL OUTLINE

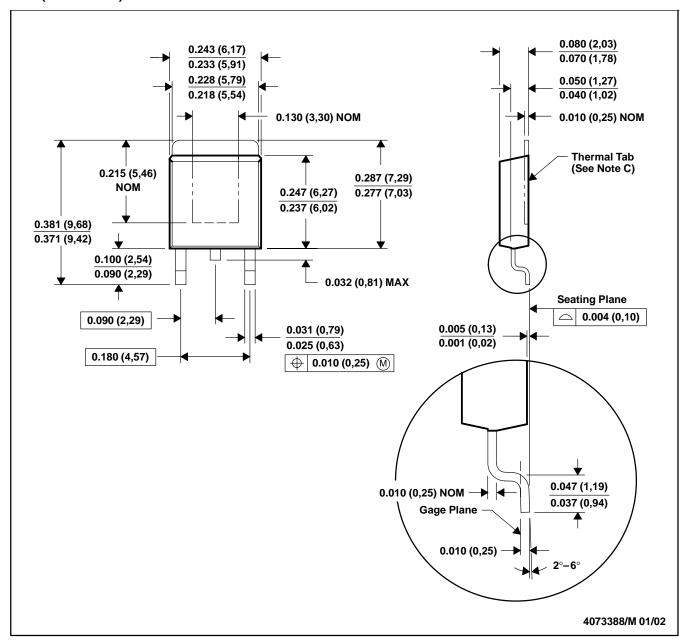


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil recommendations. Refer to IPC 7525 for stencil design considerations.



KTP (R-PSFM-G2)

PowerFLEX™ PLASTIC FLANGE-MOUNT PACKAGE



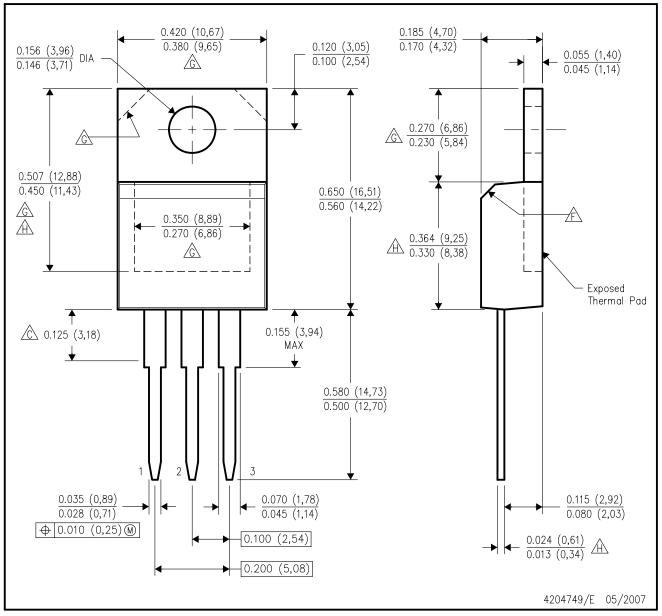
- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. The center lead is in electrical contact with the thermal tab.
 - D. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
 - E. Falls within JEDEC TO-252 variation AC.

PowerFLEX is a trademark of Texas Instruments.



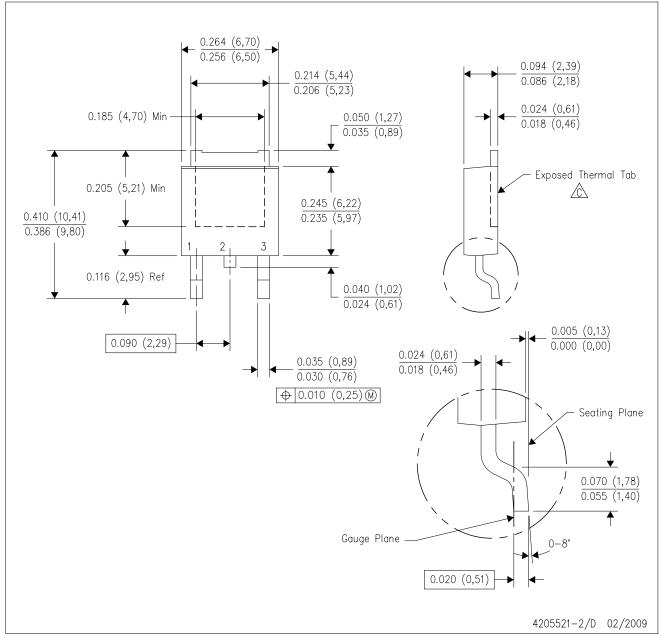
KCS (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- The chamfer is optional.
- Thermal pad contour optional within these dimensions.
- Falls within JEDEC TO-220 variation AB, except minimum lead thickness, minimum exposed pad length, and maximum body length.



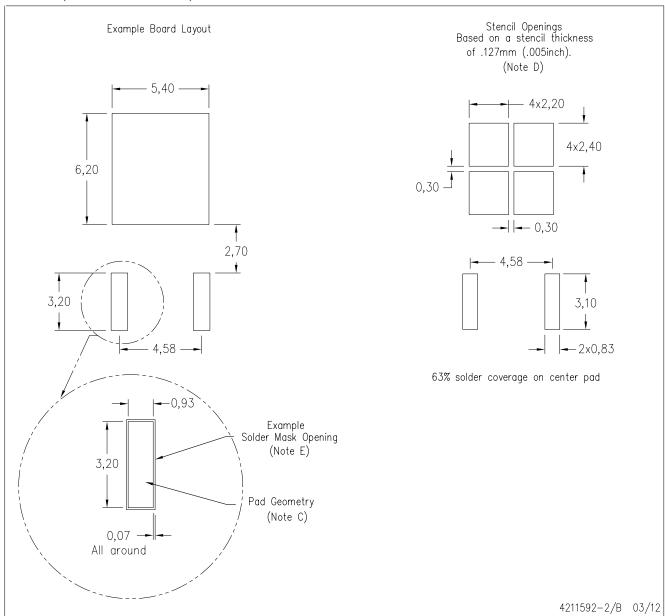


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- The center lead is in electrical contact with the exposed thermal tab.
- D. Body Dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.006 (0,15) per side.
- E. Falls within JEDEC TO-252 variation AA.



KVU (R-PSFM-G3)

PLASTIC FLANGE MOUNT PACKAGE

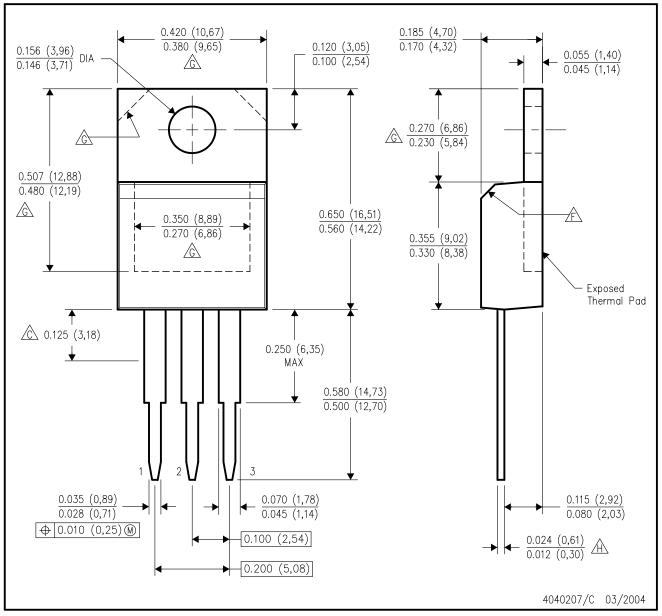


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is an alternate information source for PCB land pattern designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in thermal pad.



KC (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES: A

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- The chamfer is optional.
- Thermal pad contour optional within these dimensions.
- Falls within JEDEC TO-220 variation AB, except minimum lead thickness.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>